TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7WZ32FU,TC7WZ32FK

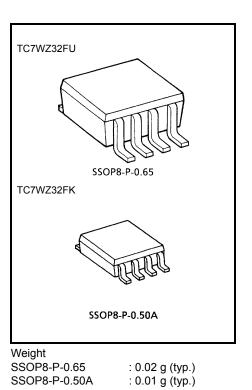
Dual 2 Input OR Gate

Features

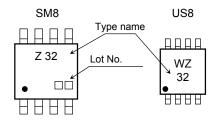
- High output drive: ±24 mA (min) at V_{CC} = 3 V
- Super high speed operation: t_{pd} = 2.4 ns (typ.)

at V_{CC} = 5 V, 50 pF

- Operation voltage range: V_{CC (opr)} = 1.65~5.5 V
- 5.5-V tolerant inputs
- 5.5-V power down protection outputs
- Matches the performance of TC74LCX series when operated at 3.3-V V_{CC}



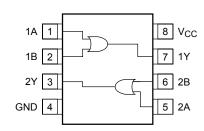
Marking





Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	-0.5~6	V	
DC input voltage	V _{IN}	-0.5~6	V	
DC output voltage	V _{OUT}	-0.5~6	V	
Input diode current	I _{IK}	-20	mA	
Output diode current	I _{OK}	-20	mA	
DC output current	lout	±50	mA	
DC V _{CC} /ground current	Icc	±50	mA	
Power dissipation	PD	300 (SM8) 200 (US8)	mW	
Storage temperature	T _{stg}	-65~150	°C	
Lead temperature (10s)	TL	260	°C	





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Truth Table

Logic Diagram

А	В	Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н



Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit	
Supply voltage	Vee	1.65~5.5	V	
Supply voltage	Vcc	1.5~5.5 (Note 1)		
Input voltage	V _{IN}	0~5.5	V	
Output voltage	V _{OUT}	0~5.5 (Note 2)	v	
		0~V _{CC} (Note 3)		
Operating temperature	T _{opr}	-40~85	°C	
	dt/dv	0~20 (V_{CC} = 1.8 V \pm 0.15 V, 2.5 V \pm 0.2 V)	ns/V	
Input rise and fall time		0~10 (V_{CC} = 3.3 V \pm 0.3 V)		
		0~5 (V _{CC} = 5.5 V \pm 0.5 V)		

Note 1: Data retention only

Note 2: $V_{CC} = 0 V$

Note 3: High or low state

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Symbol Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
Charac	Characteristics Symbol Foct Sondition		V _{CC} (V)	Min	Тур.	Max	Min	Max	Onit		
High level		Viii	_		1.65~ 1.95	$\begin{array}{c} 0.75 \\ \times V_{CC} \end{array}$	_	_	$\begin{array}{c} 0.75 \\ \times V_{CC} \end{array}$	_	- v
Input voltage	V _{IH}	2.3~5.5			$0.7 \times V_{CC}$		_	$0.7 \times V_{CC}$	_		
				1.65~ 1.95	_		0.25 × V _{CC}	_	$_{\timesV_{CC}}^{0.25}$		
	Low level	V _{IL}			2.3~5.5	_		$0.3 \times V_{CC}$		$0.3 \\ \times V_{CC}$	
					1.65	1.55	1.65	_	1.55	_	
				I _{OH} = -100 μA	2.3	2.2	2.3	—	2.2	—	
				10H - 100 μ/ τ	3.0	2.9	3.0	—	2.9		
			.,		4.5	4.4	4.5		4.4	—	
	High level	vel V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -4 \text{ mA}$	1.65	1.29	1.52	—	1.29		
				$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.15	—	1.9	—	-
				$I_{OH} = -16 \text{ mA}$	3.0	2.4	2.8	—	2.4		
				$I_{OH} = -24 \text{ mA}$	3.0	2.3	2.68	—	2.3	—	
Output				$I_{OH} = -32 \text{ mA}$	4.5	3.8	4.2	—	3.8	— v	V
voltage		level V _{OL} V	VIN = VIL	$I_{OL} = 100 \ \mu A$ $I_{OL} = 4 \ m A$	1.65	—	0	0.1	—	0.1	v
					2.3	—	0	0.1	_	0.1	
					3.0	—	0	0.1	_	0.1	-
					4.5	—	0	0.1	_	0.1	
	Low level				1.65	—	0.08	0.24	_	0.24	
				$I_{OL} = 8 \text{ mA}$	2.3	—	0.1	0.3	_	0.3	
				$I_{OL} = 16 \text{ mA}$	3.0	—	0.15	0.4	_	0.4	
				$I_{OL} = 24 \text{ mA}$	3.0	—	0.22	0.55	_	0.55	
				$I_{OL} = 32 \text{ mA}$	4.5		0.22	0.55	_	0.55	
Input leakage	current	I _{IN}	$V_{IN} = 5.5 \text{ V or GND}$		0~5.5	—	_	±1	—	±10	μA
Power off lea	kage current	IOFF	$V_{\rm IN}$ or $V_{\rm OL}$	JT = 5.5 V	0.0	—	_	1	—	10	μA
Quiescent supply current I_{CC} $V_{IN} = 5.5$ V or GND		1.65~5.5	—		1	—	10	μA			

AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
Propagation delay time	^t pLH t _{pHL}	C_L = 15 pF, R_L = 1 M Ω C_L = 50 pF, R_L = 500 Ω	1.8 ± 0.15	2.0	5.8	10.5	2.0	11.0	ns
			2.5 ± 0.2	1.0	3.5	5.8	1.0	6.2	
			$\textbf{3.3}\pm\textbf{0.3}$	0.8	2.6	3.9	0.8	4.3	
			5.0 ± 0.5	0.5	1.8	3.1	0.5	3.3	
			$\textbf{3.3}\pm\textbf{0.3}$	1.2	3.2	4.8	1.2	5.2	
			5.0 ± 0.5	0.8	2.4	3.7	0.8	4.0	
Input capacitance	CIN	—	0~5.5	_	3.0	_	_	_	pF
Power dissipation capacitance	C _{PD} (Note	(Note 4)	3.3	_	20	_			рF
		(Note 4)	5.5	_	26				

Note 4:C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

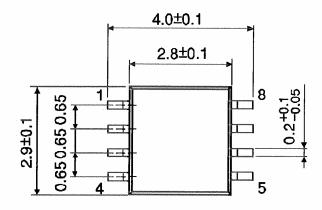
 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$

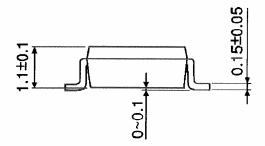
TOSHIBA

Package Dimensions

SSOP8-P-0.65

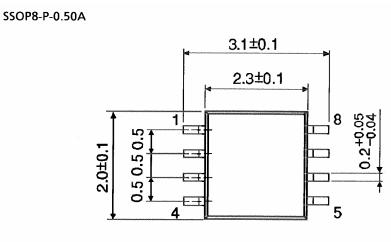
Unit : mm

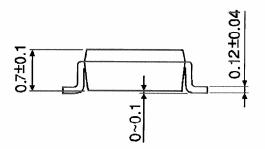




Weight: 0.02 g (typ.)

Package Dimensions





Weight: 0.01 g (typ.)

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Unit : mm

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